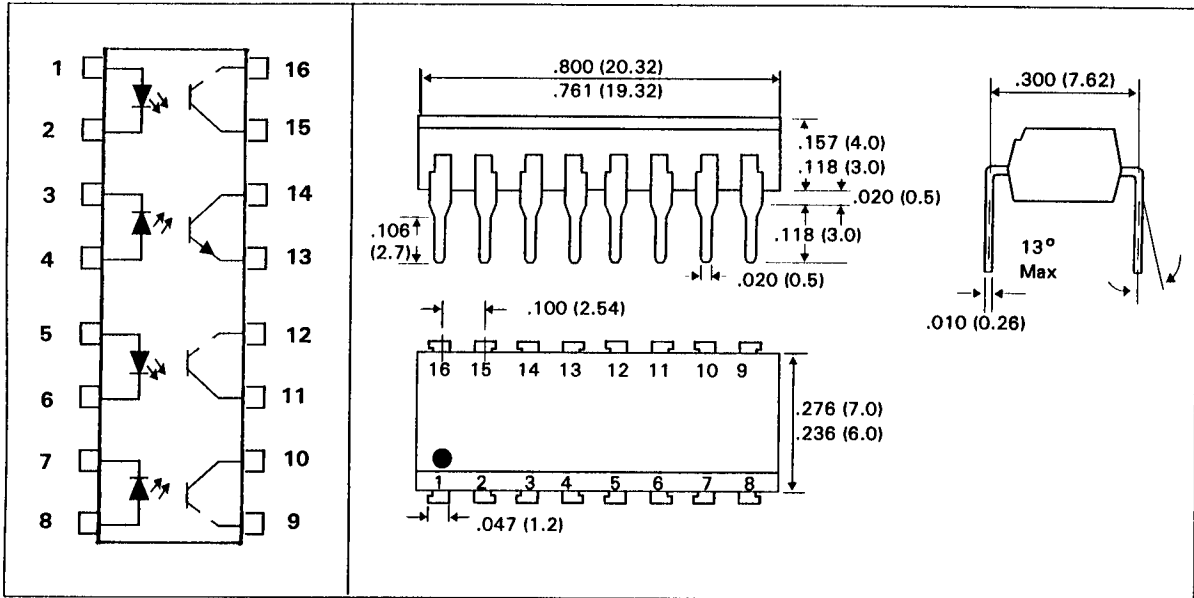


Order code	Manufacturer code	Description
58-0150	ISQ-74	QUAD OPTOISOLATOR ISQ74

	Page 1 of 3
The enclosed information is believed to be correct, Information may change 'without notice' due to product improvement. Users should ensure that the product is suitable for their use. E. & O. E.	Revision A 04/07/2003

SCHEMATIC

PACKAGE DIMENSIONS INCHES (MM)



DESCRIPTION

The ISQ74 is an optically coupled isolator consisting of Gallium Arsenide infrared emitting diodes and NPN silicon phototransistors mounted in a standard 16-pin dual-in-line package with four channels per unit.

FEATURES

- Also available in single, dual package

ABSOLUTE MAXIMUM RATINGS (25°C unless otherwise noted)

Storage Temperature	-55°C to +125°C
Operating Temperature	-55°C to +100°C
Lead Soldering Temperature (2mm from case for 10 seconds)	260°C
Input-to-Output Isolation Voltage	7500VpK

INPUT DIODE

Forward D.C. Current	_____	60mA
Reverse D.C. Voltage	_____	3V
Peak Forward Current (p.w. ≤ 100µs, duty ratio 0.001)	_____	1A
Power Dissipation (derate linearly 1.33mW/°C above 25°C)	_____	100mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV_{CEO}	_____	30V
Power Dissipation (derate linearly 2.00mW/°C above 25°C)	_____	150mW

PACKAGE

Total Power Dissipation (derate linearly 5.33mW/°C above 25°C)	_____	400mW
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ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)		1.3	1.5	Volt	$I_F = 60 \text{ mA}$
	Reverse Current (I_R)			10	μA	$V_R = 3\text{V}$
Output	Collector-emitter Voltage (BV_{CEO})	30	50		Volt	$I_C = 1\text{mA}$
	Emitter-collector Voltage (BV_{ECO})	7	9		Volt	$I_E = 0.1 \text{ mA}$
	Collector-emitter Dark Current (I_{CEO})			50	nA	$V_{CE} = 10 \text{ V}$
Coupled	DC Current Transfer Ratio (CTR)	12.5			%	$I_F = 16\text{mA}, V_{CE} = 5\text{V}$
	Collector-emitter Saturation Voltage $V_{CE}(\text{Sat})$		0.3	0.5	Volt	$I_F = 16 \text{ mA}, I_C = 2 \text{ mA}$
	Floating Capacitance (C_F)		0.5	10	pf	$V = 0, f = 1 \text{ Mhz}$
	Input-to-Output Isolation Resistance R_{iso}	10^{12}	10^{13}		ohm	$V_{IO} = 500\text{V}$ (see note 1)
	Inout to Output Isolation Voltage	7500			Vpk	(note 1)
	Output Turn - on Time (t_{on})		3.0		μS	$I_C = 2\text{mA}, V_{CC} = 10\text{V}$ $R_L = 100\text{R}$
Output Turn - off Time (t_{off})		2.5		μS	Fig 1	

Note 1. Measured with input leads shorted together and output leads shorted together.

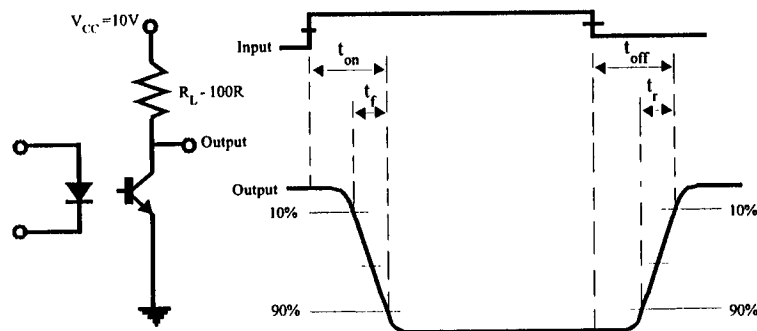


FIG 1